

XL93LC66/66A

4,096-Bit Serial Electrically Erasable PROM with 2V Read Capability

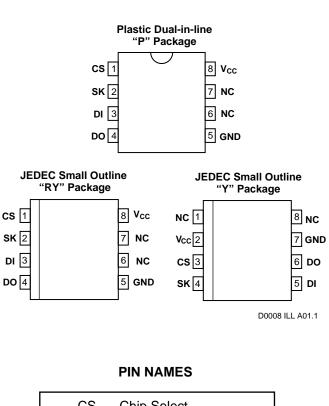
PIN CONFIGURATIONS

FEATURES

- 2.7 to 5.5V Operation (XL93LC66) 4.5 to 5.5V Operation (XL93LC66A)
- Extended Temperature Range: -40°C to +85°C
- State-of-the-Art Architecture
 - Nonvolatile data storage
 - Fully TTL compatible inputs and outputs
 - Auto increment for efficient data dump
- Hardware and Software Write Protection
 - Defaults to write-disabled state at power up
 - Software instructions for write-enable/disable
 - VCC lockout inadvertent write protection (XL93LC66A)
- Low Power Consumption
 - 1mA active
 - 1µA standby
 - Low Voltage Read Operations
 - Reliable read operations down to 2.0 volts
- Advanced Low Voltage CMOS E²PROM Technology
- Versatile, Easy-to-Use Interface
 - Self-timed programming cycle
 - Automatic erase-before-write
 - Programming Status Indicator
 - Word and chip erasable
- Durable and Reliable
 - 100-year data retention after 100K write cycles
 - Minimum of 100,000 erase/write cycles
 - Unlimited read cycles
 - ESD protection (EIAJ and JEDEC Protection)

OVERVIEW

The XL93LC66/66A is a cost effective 4,096-bit, nonvolatile, serial E²PROM. It is fabricated using EXEL's advanced CMOS E²PROM technology. The XL93LC66/ 66A provides efficient nonvolatile read/write memory arranged as 256 registers of 16 bits each. Seven 11-bit instructions control the operation of the device, which include read, write, and mode enable functions. The data output pin (DO) indicates the status of the device during the self-timed nonvolatile programming cycle.

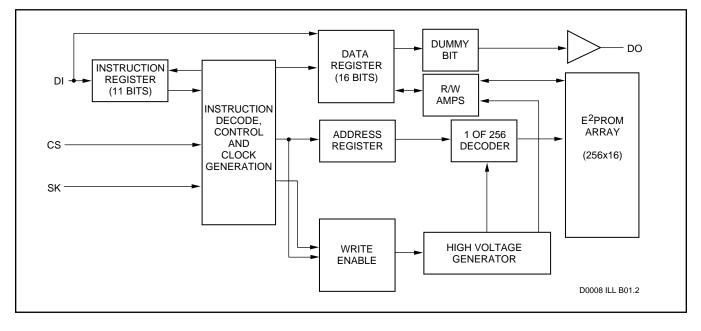


CS	Chip Select
SK	Serial Data Clock
DI	Serial Data Input
DO	Serial Data Output
GND	Ground
Vcc	Power Supply
NC	Not Connected

The self-timed write cycle includes an automatic erasebefore-write capability. To protect against inadvertent writes, the WRITE instruction is accepted only while the chip is in the write enabled state. Data is written in 16 bits per write instruction into the selected register. If Chip Select (CS) is brought HIGH after initiation of the write cycle, the Data Output (DO) pin will indicate the READY/ BUSY status of the chip.



BLOCK DIAGRAM



APPLICATIONS

The XL93LC66/66A is ideal for high volume applications requiring low power and low density storage. This device uses a cost effective, space saving 8-pin package. Candidate applications include robotics, alarm devices, electronic locks, meters and instrumentation settings.

ENDURANCE AND DATA RETENTION

The XL93LC66/66A is designed for applications requiring up to 100,000 erase/write cycles. It provides 100 years of secure data retention without power after the execution of 100,000 write cycles.

DEVICE OPERATION

The XL93LC66/66A is controlled by seven 11-bit instructions. Instructions are clocked in (serially) on the DI pin. Each instruction begins with a logical "1" (the start bit). This is followed by the opcode (2 bits), the address field (8 bits), and data, if appropriate. The clock signal (SK) may be halted at any time and the XL93LC66/66A will remain in its last state. This allows full static flexibility and maximum power conservation.

Read (READ)

The READ instruction is the only instruction that results in serial data on the DO pin. After the read instruction and address have been decoded, data is transferred from the selected memory register into a 16-bit serial shift register. (Please note that one logical "0" bit precedes the actual 16-bit output data string). The output on DO changes during the LOW-TO-HIGH transitions of SK. (See Figure 2.) DOOD8 3/96 DVPTD 6931-04

Low Voltage Read

The XL93LC66/66A has been designed to ensure that data read operations are reliable in low voltage environments. The XL93LC66/66A is guaranteed to provide accurate data during read operations with V_{CC} as low as 2.0V.

Auto Increment Read Operations

In order to facilitate memory transfer operations, the XL93LC66/66A has been designed to output a continuous stream of memory content in response to a single read operation instruction. To utilize this function, the system asserts a read instruction specifying a start location address. Once the 16 bits of the addressed word have been clocked out, the data in consecutively higher address locations is output. The address will wrap around continuously with CS HIGH until the Chip Select control pin is brought LOW. This allows for single instruction data dumps to be executed with a minimum of firmware overhead.

Write Enable (WEN)

The write enable (WEN) instruction must be executed before any device programming can be done. When V_{CC} is applied, this device powers up in the write disabled state. The device then remains in a write disabled state until a WEN instruction is executed. Thereafter the device remains enabled until a WDS instruction is executed or until V_{CC} is removed. (NOTE: Neither the WEN nor the WDS instruction has any effect on the READ instruction. See Figure 3.)





Write (WRITE)

The WRITE instruction includes 16 bits of data to be written into the specified register. After the last data bit has been clocked into DI, and before the next rising edge of SK, CS must be brought LOW. The falling edge of CS initiates the self-timed programming cycle.

After a minimum wait of 250ns from the falling edge of CS (t_{CS}), if CS is brought HIGH, DO will indicate the READY/ BUSY status of the chip: logical "0" means programming is still in progress; logical "1" means the selected register has been written, and the part is ready for another instruction. (See Figure 4). (NOTE: The combination of CS HIGH, DI HIGH and the rising edge of the SK clock, resets the READY/BUSY flag. Therefore, it is important not to reset the READY/BUSY flag through this combination of control signals, if you need to access it.) Before a WRITE instruction can be executed, the device must be write enabled (see WEN).

Write All (WRALL)

The write all (WRALL) instruction programs all registers with the data pattern specified in the instruction. As with the WRITE instruction, if CS is brought HIGH after a minimum wait of 250ns (t_{CS}), the DO pin indicates the READY/BUSY status of the chip. (See Figure 5.)

Write Disable (WDS)

The write disable (WDS) instruction disables all programming capabilities. This protects the entire memory array against accidental modification of data until a WEN instruction is executed. (When V_{CC} is applied, the part powers up in the write disabled state). To protect data, a WDS instruction should be executed upon completion of each programming operation. (NOTE: Neither the WEN nor the WDS instruction has any effect on the READ instruction. See Figure 6).

Erase

The Erase instruction (ERASE) programs the addressed memory byte or word to all "1s." Once the address is clocked in, the falling edge of CS will initiate the internal programming cycle. After waiting a minimum 250ns, the READY/BUSY status can be monitored on DO.

Erase All (ERAL)

Full chip erase is provided for ease of programming. Erasing the entire chip involves setting all bits in the entire memory array to a logical "1." (See Figure 8).

V_{CC} Lockout - Inadvertent Write Protection (XL93LC66A only)

To ensure against inadvertent write operations, the XL93LC66A has been equipped with an internal V_{CC} sensor circuit which inhibits data alteration when the supply voltage (V_{CC}) falls below V_{WI} . If the applied V_{CC} is below 3.75V (typical), the XL93LC66A is inhibited from executing write operations thereby protecting the non-volatile data from inadvertent write operations.

Instruction	Start Bit	OP Code	Address	Input Data
READ	1	10	(A7-A0)	
WEN (Write Enable)	1	00	11XXXXXX	
WRITE	1	01	(A7-A0)	D ₁₅ -D ₀
WRALL (Write All Registers)	1	00	01XXXXXX	D ₁₅ -D ₀
WDS (Write Disable)	1	00	00XXXXXX	
ERASE	1	11	(A7-A0)	
ERAL (Erase All Registers)	1	00	10XXXXXX	

XL93LC66/66A INSTRUCTION SET

D0008 PGM T01.2



ABSOLUTE MAXIMUM RATINGS

Temperature under bias:	-40°C to +85°C
Storage Temperature	-65°C to +150°C
Lead Soldering Temperature (less than 10 seconds)	
Supply Voltage	
Voltage on Any Pin	
ESD Rating	
NOTE: These are STRESS ratings only. Appropriate conditions for operating these devices are given el	

beyond those listed here may permanently damage the part. Prolonged exposure to maximum ratings may adversely affect device reliability.

DC ELECTRICAL CHARACTERISTICS

 $TA = -40^{\circ}C$ to $+85^{\circ}C$

		Conditions	XL93LC66 Vcc = 3.0V±10%		XL93LC66/66A Vcc = 5.0V±10%		XL93LC66/66A Vcc = 2.0V (Read Only)		Units
Symbol	Parameter								
			Min	Max	Min	Max	Min	Max	
I _{CC1}	Operating Current CMOS Input Levels	CS = VCC, SK = 250KHz		2		2		2	mA
I _{CC2}	Operating Current TTL Input Levels	$CS = V_{IH}, SK = 1MHz$		n/a		5		n/a	mA
I _{SB}	Standby Current	CS = DI = SK =0V		2		2		2	μA
Ι _{LI}	Input Leakage	$V_{IN} = 0V$ to V_{CC} (CS, SK, DI)		1		1		1	μA
I _{LO}	Output Leakage	$V_{OUT} = 0V$ to V_{CC} , $CS = 0V$		1		1		1	μA
V _{IL}	Input Low Voltage		-0.1	0.15Vcc	-0.1	0.8	-0.1	0.1 Vcc	V
V _{IH}	Input High Voltage		0.8 VCC	Vcc+0.2	2	Vcc	0.9 VCC	VCC+0.2	V
V _{OL1}	Output Low Voltage	I _{OL} = 2.1mA TTL		n/a		0.4		n/a	V
V _{OH1}	Output High Voltage	I _{OH} = -400μΑ TTL	n/a		2.4		n/a		V
V _{OH2}	Output High Voltage	I _{OH} = -10μA CMOS		0.2		0.2		0.2	V
V _{OH2}	Output High Voltage	I _{OH} = -10μA CMOS	Vcc-0.2		Vcc-0.2		Vcc-0.2		V
V _{WI}	Write Inhibit Threshold		n/a	n/a	2.7	4.4	n/a	n/a	V

D0008 PGM T02.1

AC ELECTRICAL CHARACTERISTICS $T_A = -40^{\circ}C$ to $+85^{\circ}C$

	Parameter	Conditions	XL93LC66 V _{CC} = 3.0V±10%		XL93LC66/66A V _{CC} = 5.0V±10%		XL93LC66/66A V _{CC} = 2.0V (Read Only)		Units
Symbol									
			Min	Max	Min	Max	Min	Max	
fsĸ	SK Clock Frequency		0	250	0	1000	0	250	KHz
tsкн	SK High Time		1000		400		2000		ns
t SKL	SK Low Time		1000		250		2000		ns
tcs	Minimum CS Low Time		1000		250		1000		ns
tcss	CS Setup Time	Relative to SK $_$	200		50		200		ns
tDIS	DI Setup Time	Relative to SK	400		100		400		ns
tcsн	CS Hold Time	Relative to SK	0		0		0		ns
tdih	DI Hold Time	Relative to SK $_$	400		100		400		ns
tPD1	Output Delay to "1"	AC Test		2000		500		2000	ns
tPD0	Output Delay to "0"	AC Test		2000		500		2000	ns
tsv	CS to Status Valid	AC Test CL = 100pF		2000		500		2000	ns
tDF	CS to DO in 3-state	CS = Low to DO = Hi-Z		400		100		400	ns
twp	Write Cycle Time	CS = Low to DO = Ready		25		10		n/a	ms

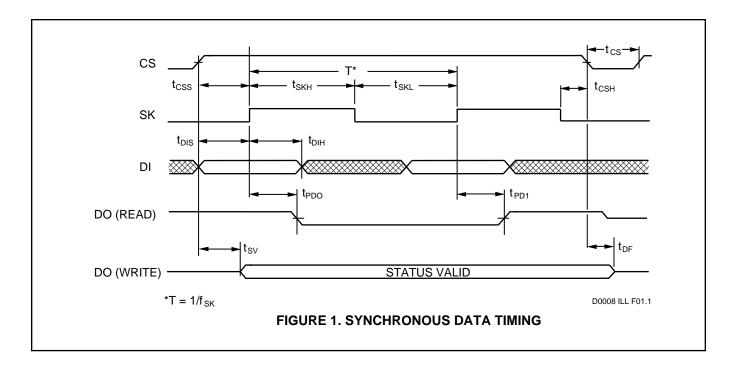


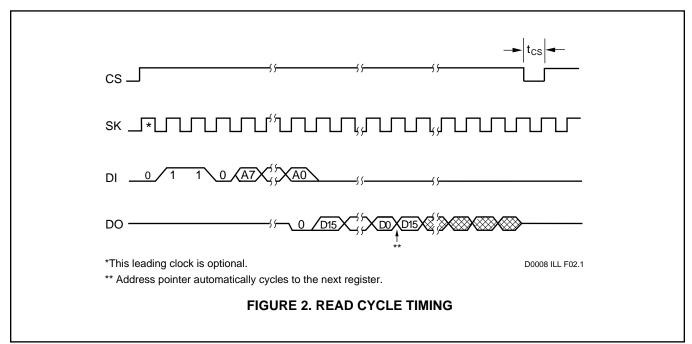
CAPACITANCE

 $T_A = 25^{\circ}C$, f = 250KHz

Symbol	Parameter	Мах	Units	
C _{IN}	Input Capacitance	5	pF	
COUT	Output Capacitance	5	pF	

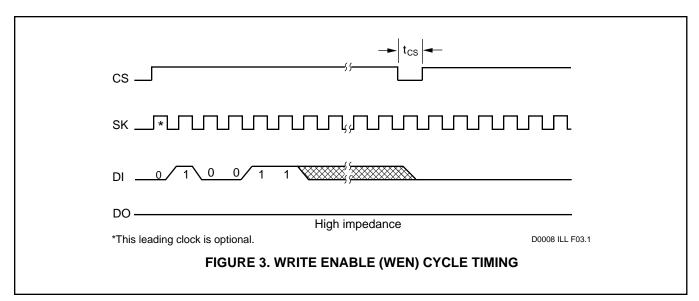
D0008 PGM T04.1

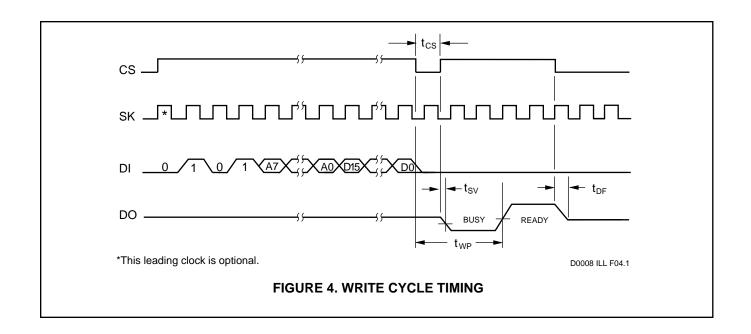






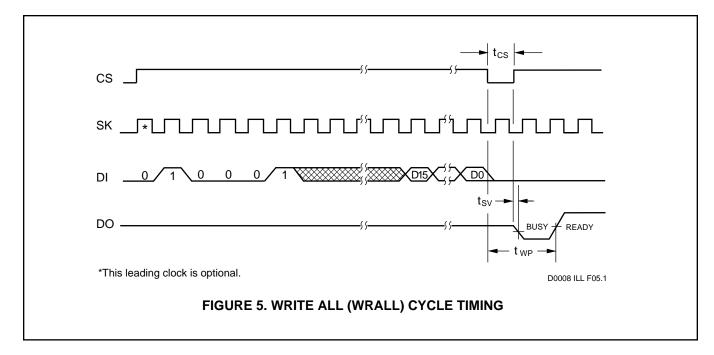


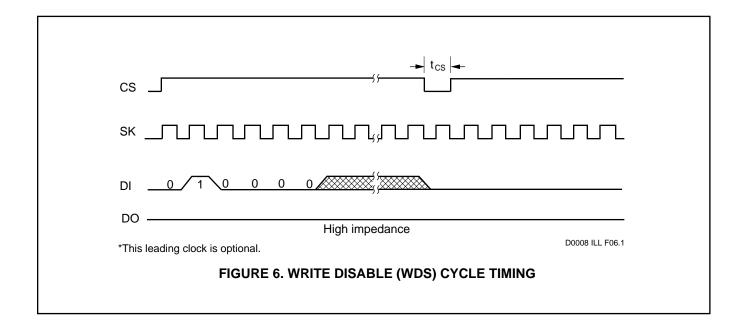






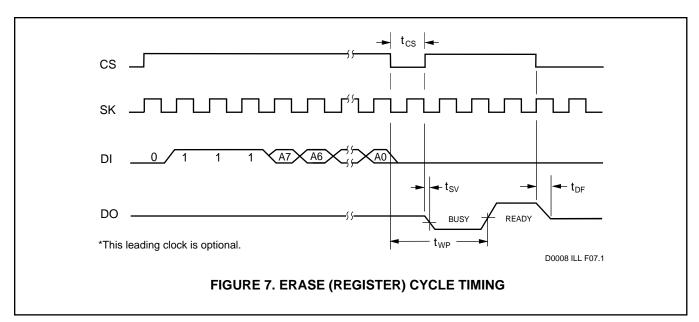


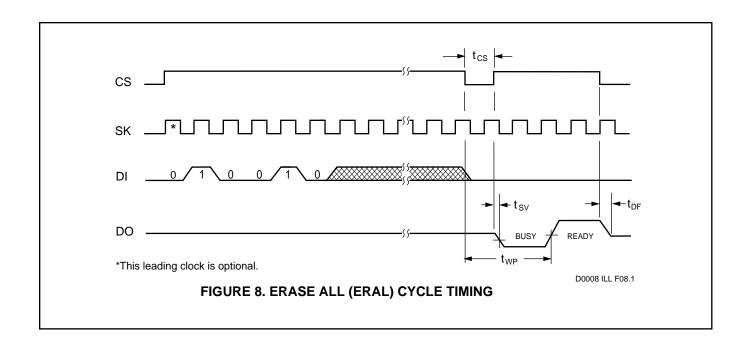






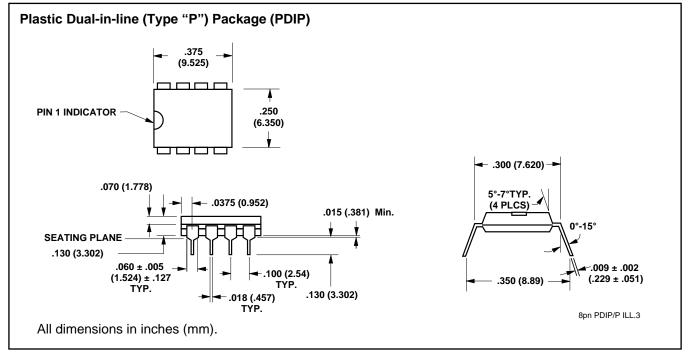


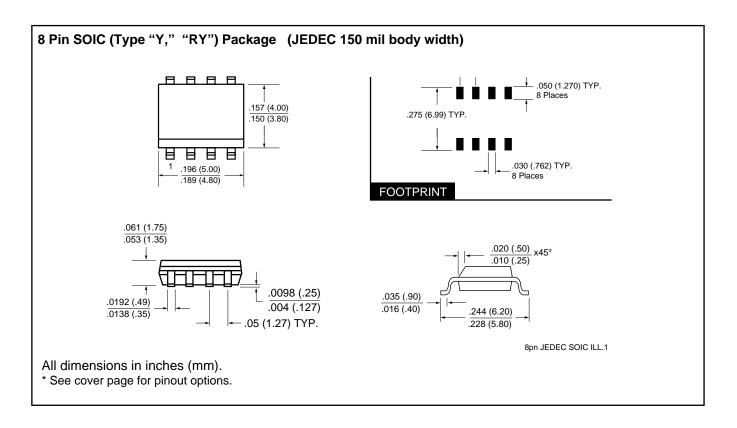






PACKAGE DIAGRAMS







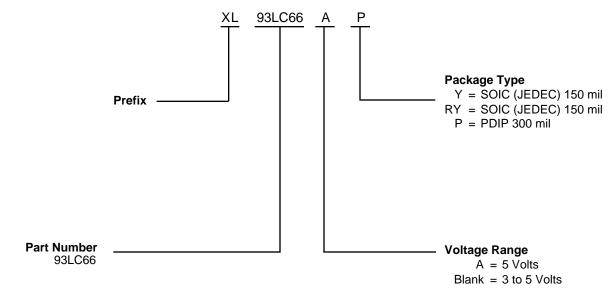
ORDERING INFORMATION

Standard Configurations

Prefix	Part	Voltage	Package	
Type	Type		Range	
XL	93LC66	3 Volts, 5 Volts	P, Y, RY	

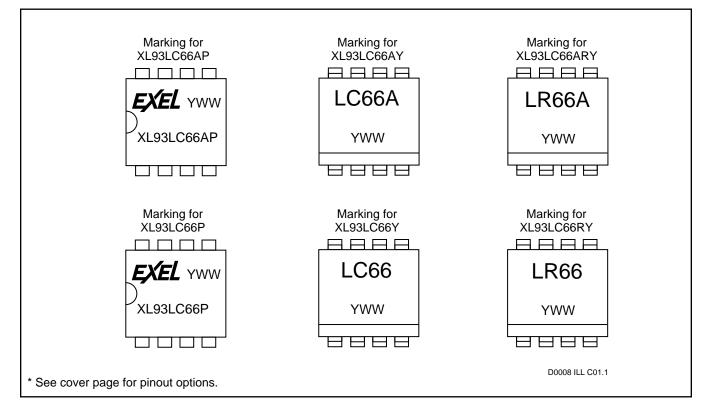
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Part Numbers:



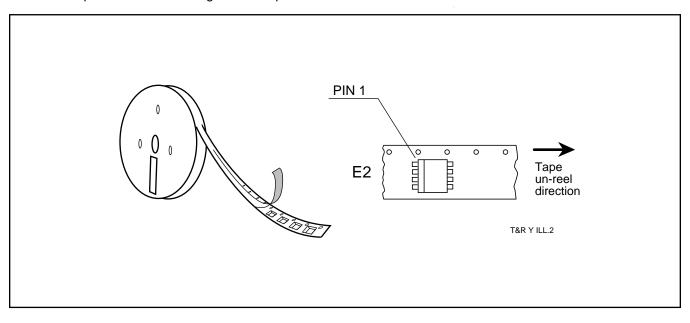


MARKING INFORMATION



TAPE AND REEL (EMBOSSED) INFORMATION

Surface mount devices, which are normally shipped in antistatic plastic tubes, are also available mounted on embossed tape for customers using automatic placement systems. The following diagram provides general information regarding the direction of the IC's. Tape "E2" shall be designated with PIN 1 at the trail direction.





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